

Electronic Supplementary Information for Decomposition of Hydrogen Sulfide in Non-Thermal Plasma Aided by Supported CdS and ZnS Semiconductors

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Experimental Section

Al₂O₃-supported metal oxide precursors were prepared by impregnation from their salts and Al₂O₃. A loading level of 10 wt% oxide precursor was chosen for each catalyst. For example, CdO/Al₂O₃ was prepared as follows: γ -Al₂O₃ extrudes (surface area: 270 m²/g) were crushed and sieved to 40-60 mesh. 4.0 g Cd(NO₃)₂·4H₂O was dissolved in 15.0 mL de-ionized water. The resulting solution was mixed with 15.0 g γ -Al₂O₃ pellets, which were kept at room temperature for 8 h. Then the mixture was dried at 120 °C for 12 h, followed by calcination at 450 °C for 5 h. CdS/Al₂O₃ (surface area: 205 m²/g) and ZnS/Al₂O₃ (surface area: 213 m²/g) were obtained by sulfidation of the oxide precursors at 400 °C for 180 min in a 10% H₂S/Ar flow (80 mL/min). H₂S decomposition was carried out in a DBD reactor, which mainly consisted of a quartz tube and two electrodes (Fig. S1, ESI†). The high-voltage electrode was a stainless-steel rod with a diameter of 2.5 mm, which was installed in the axis of the quartz tube and connected to an alternating current supply. The grounding electrode was an aluminum foil, which was wrapped around the quartz tube and was connected to ground by a wire. 15.0 mL of Al₂O₃ or the supported catalyst were charged into the gap between the quartz tube and the high-voltage electrode. The reactor was immersed in an oil bath, which was kept at 120 °C. A flow of 20% H₂S in Ar (30 mL/min) was passed through the catalyst bed while a head-to-head voltage (10 kHz) was applied to generate a non-thermal plasma by DBD. The effluent was passed through a saturated NaOH solution trap to remove unreacted H₂S, and the hydrogen content was analyzed by an on-line gas chromatograph equipped with a thermal conductivity detector. At full conversion, the effluent was rechecked with lead acetate test paper. Specific input energy (SIE) was determined by the discharge power divided by gas flow rate. The discharge power was calculated using the Q-V Lissajous diagram, which was measured by a digital oscilloscope. The energy consumption cost in terms of hydrogen production was calculated from the SIE and H₂ yield. The supported metal sulfides, fresh and spent, were characterized by XRD (Rigaku D/Max 2400) to determine their crystal phases.

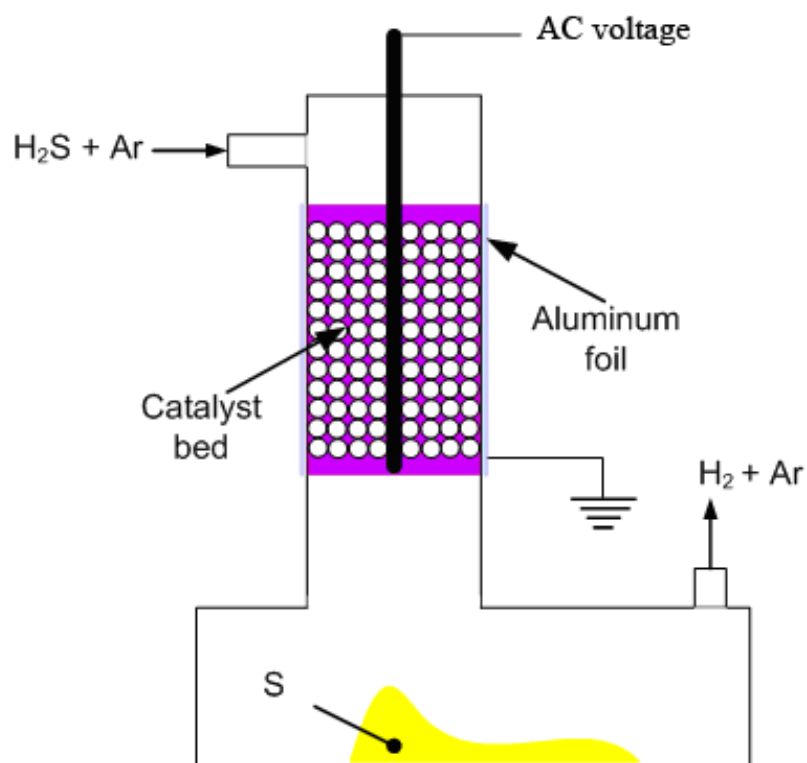


Fig. S1 Schematic diagram of the DBD reactor for plasma-induced H_2S decomposition.

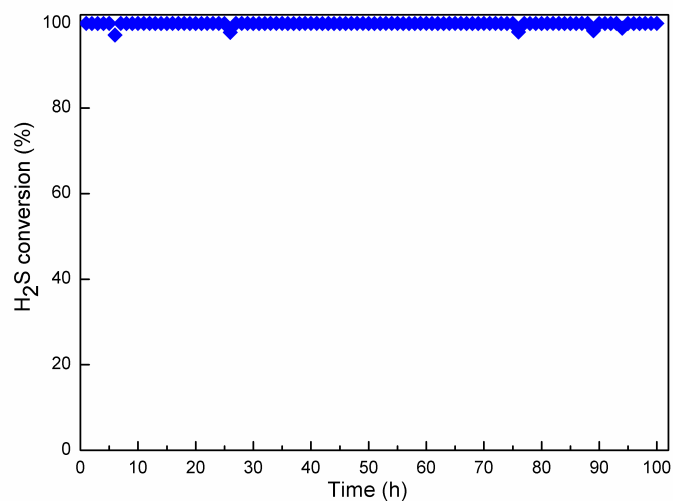


Fig. S2 Variation of H_2S conversion with time in the plasma-induced splitting over CdS/Al_2O_3 . Reaction conditions: SIE of 6 kJ/L; feed: 20% H_2S in Ar; GHSV $120\ h^{-1}$; catalyst bed volume: 15.0 mL.

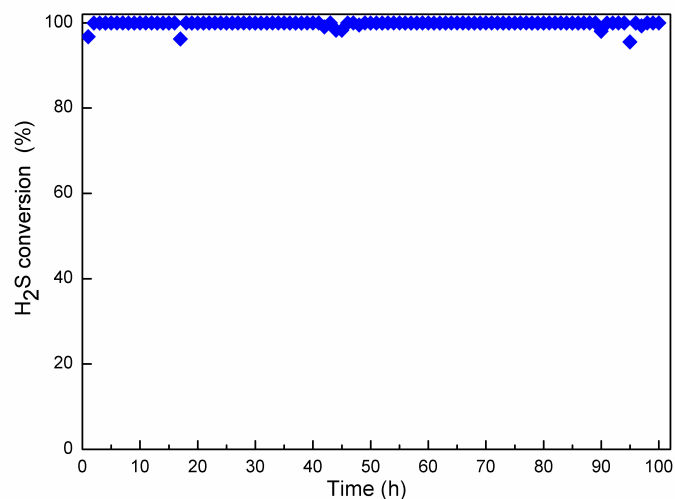


Fig. S3 Variation of H₂S conversion with time in the plasma-induced splitting over ZnS/Al₂O₃. Reaction conditions: SIE of 8 kJ/L; feed: 20% H₂S in Ar; GHSV 120 h⁻¹; catalyst bed volume: 15.0 mL.

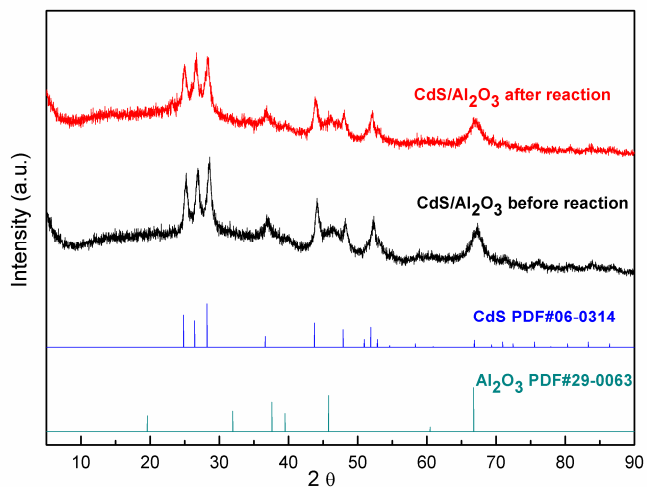


Fig. S4 XRD patterns of CdS/Al₂O₃ catalyst before and after H₂S decomposition reaction.

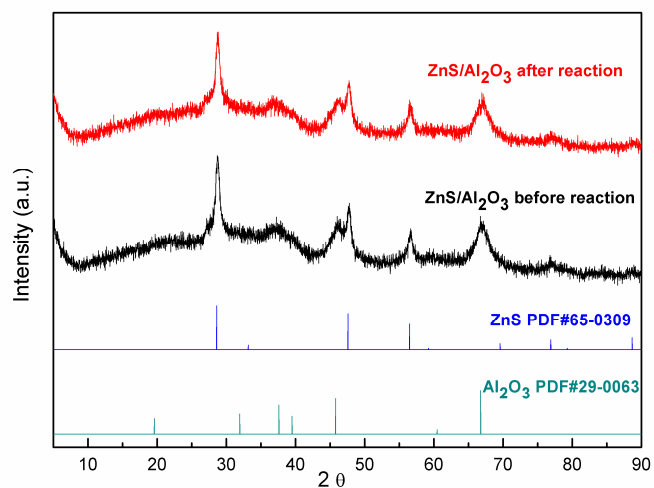


Fig. S5 XRD patterns of ZnS/Al₂O₃ catalyst before and after H₂S decomposition reaction.

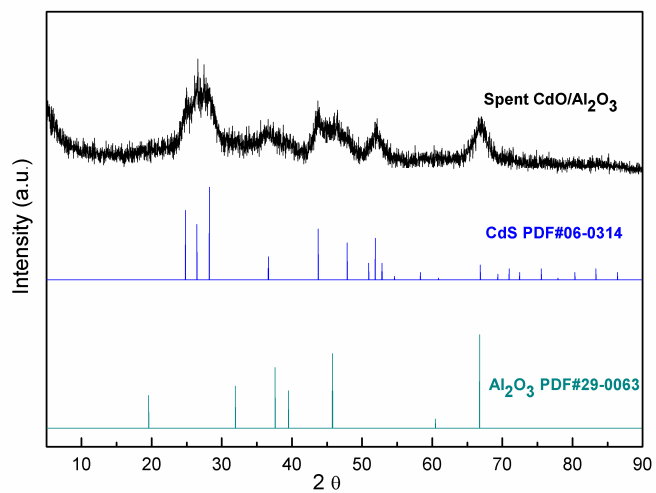


Fig. S6 XRD patterns of spent CdO/Al₂O₃ catalyst.

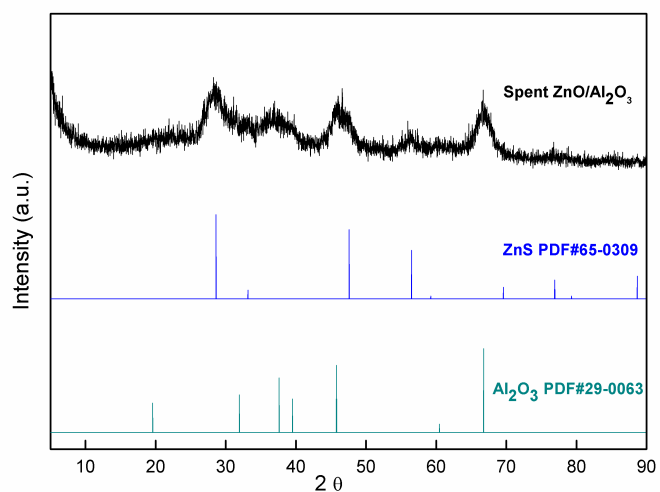


Fig. S7 XRD patterns of spent ZnO/Al₂O₃ catalyst.

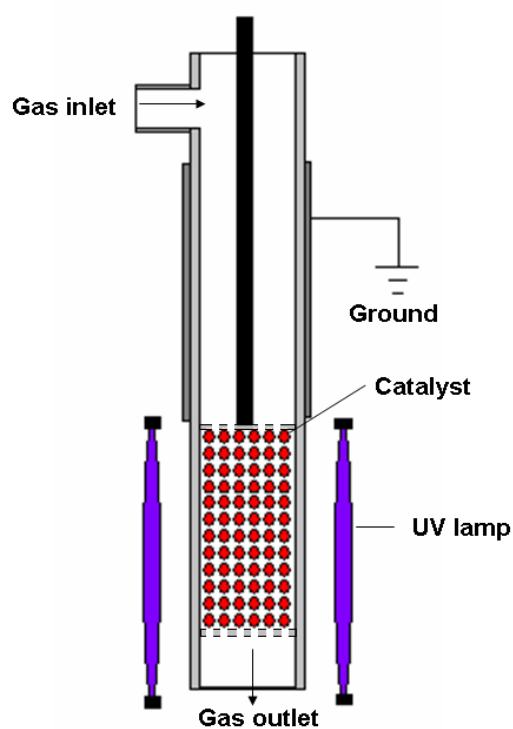


Fig. S8 Schematic diagram of the DBD reactor with a downstream photocatalyst bed.

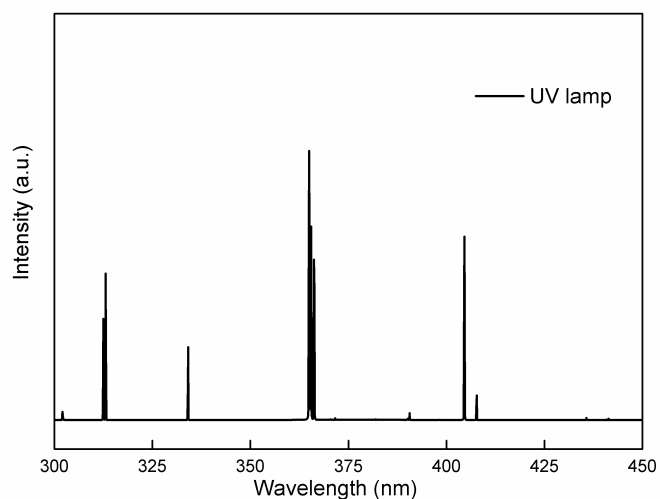


Fig. S9 Emission spectral analysis of the UV lamp.

Table S1 Conversion and dissociation energy cost as a function of SIE in the plasma-induced H₂S decomposition.

Material in gap	SIE (kJ/L)	H ₂ S conversion (%)	Dissociation energy cost (eV/H ₂)
CdS/Al ₂ O ₃	0.36	36.7	1.14
	0.55	42.9	1.50
	0.80	51.8	1.81
	1.05	61.0	2.01
ZnS/Al ₂ O ₃	0.60	40.6	1.72
	0.95	45.1	2.46
	1.36	51.5	3.09
	1.70	56.5	3.52